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PBLS1503Y; PBLS1503V 15 V PNP BISS loadswitch Rev. 03 – 24 August 2009 Pr

1. Product profile

1.1 General description

Low V_{CEsat} PNP transistor and NPN resistor-equipped transistor in one package.

Table 1. Product overview

Type number	Package		
	NXP	JEITA	
PBLS1503Y	SOT363	SC-88	
PBLS1503V	SOT666	-	

1.2 Features

- Low V_{CEsat} (BISS) and resistor-equipped transistor in one package
- Low 'threshold' voltage (< 1 V) compared to MOSFET</p>
- Low drive power required
- Space-saving solution
- Reduction of component count

1.3 Applications

- Supply line switches
- Battery charger switches
- High-side switches for LEDs, drivers and backlights
- Portable equipment

1.4 Quick reference data

Table 2.	Quick reference data					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
TR1; PNF	; low V _{CEsat} transistor					
V_{CEO}	collector-emitter voltage	open base	-	-	–15	V
l _C	collector current (DC)		-	-	-500	mA
R _{CEsat}	equivalent on-resistance	$I_{C} = -500 \text{ mA};$ $I_{B} = -50 \text{ mA}$	-	300	500	mΩ
TR2; NPN	I; resistor-equipped transiste	or				
V_{CEO}	collector-emitter voltage	open base	-	-	50	V



PBLS1503Y; PBLS1503V

15 V PNP BISS loadswitch

Table 2.	Quick reference data continued					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
lo	output current (DC)		-	-	100	mA
R1	bias resistor 1 (input)		7	10	13	kΩ
R2/R1	bias resistor ratio		0.8	1	1.2	

2. Pinning information

Table 3.	Discrete pinning		
Pin	Description	Simplified outline	Symbol
1	emitter TR1		
2	base TR1	6 5 4	
3	output (collector) TR2		
4	GND (emitter) TR2		
5	input (base) TR2		
6	collector TR1	001aab555	1 2 3 sym036

3. Ordering information

Table 4. Ordering information				
Type number Package				
	Name	Description	Version	
PBLS1503Y	SC-88	plastic surface mounted package; 6 leads	SOT363	
PBLS1503V	-	plastic surface mounted package; 6 leads	SOT666	

4. Marking

Table 5.Marking codes

Type number	Marking code ^[1]
PBLS1503Y	*C3
PBLS1503V	C3

[1] * = -: made in Hong Kong

- * = p: made in Hong Kong
- * = t: made in Malaysia
- * = W: made in China

15 V PNP BISS loadswitch

5. Limiting values

Symbol	Parameter	Conditions	Min	Max	Unit
Transistor	TR1: PNP				
V _{CBO}	collector-base voltage	open emitter	-	-15	V
V _{CEO}	collector-emitter voltage	open base	-	-15	V
V _{EBO}	emitter-base voltage	open collector	-	-6	V
I _C	collector current (DC)		-	-500	mA
I _{CM}	peak collector current	$t_p \le 1 ms; \delta \le 0.02$	-	-1	А
I _B	base current (DC)		-	-50	mA
I _{BM}	peak base current	$t_p \leq 1 \ ms; \delta \leq 0.02$	-	-100	mA
P _{tot}	total power dissipation	$T_{amb} \le 25 \ ^{\circ}C$	<u>[1]</u> -	200	mW
Transistor	TR2: NPN				
V _{CBO}	collector-base voltage	open emitter	-	50	V
V _{CEO}	collector-emitter voltage	open base	-	50	V
V _{EBO}	emitter-base voltage	open collector	-	10	V
VI	input voltage		-		
	positive		-	+40	V
	negative		-	-10	V
lo	output current (DC)		-	100	mA
I _{CM}	peak collector current		-	100	mA
P _{tot}	total power dissipation	$T_{amb} \le 25 \ ^{\circ}C$	<u>[1]</u> -	200	mW
Per device)				
P _{tot}	total power dissipation	$T_{amb} \le 25 \ ^{\circ}C$	-	300	mW
T _{stg}	storage temperature		-65	+150	°C
Tj	junction temperature		-	150	°C
T _{amb}	ambient temperature		-65	+150	°C

[1] Device mounted on a FR4 printed-circuit board, single-sided copper, tin-plated and standard footprint.

6. Thermal characteristics

Table 7.	Thermal characteristics					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Per devic	e					
R _{th(j-a)}	thermal resistance from junction to ambient	in free air				
	SOT363		<u>[1]</u> _	-	416	K/W
	SOT666		[1][2] _	-	416	K/W

[1] Device mounted on a FR4 printed-circuit board, single-sided copper, tin-plated and standard footprint.

[2] Reflow soldering is the only recommended soldering method.

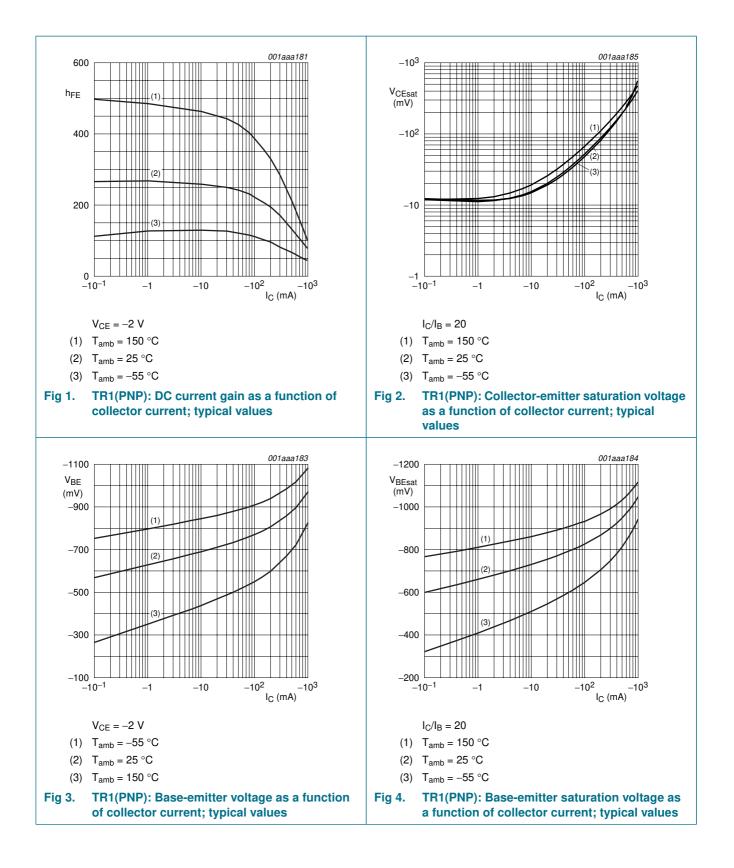
15 V PNP BISS loadswitch

7. Characteristics

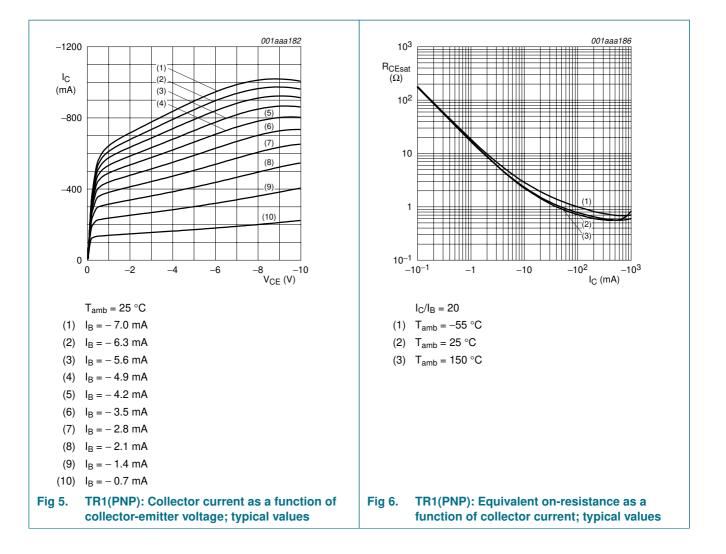
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Transistor	TR1: PNP						
I _{CBO}	collector-base cut-off	$V_{CB} = -15 \text{ V}; \text{ I}_{E} = 0 \text{ A}$		-	-	-100	nA
	current	$V_{CB} = -15 \text{ V}; \text{ I}_{E} = 0 \text{ A}; \text{ T}_{j} = 150 ^{\circ}\text{C}$		-	-	-50	μA
I _{CES}	collector-emitter cut-off current	$V_{CE} = -15 \text{ V}; V_{BE} = 0 \text{ V}$		-	-	-100	nA
I _{EBO}	emitter-base cut-off current	$V_{EB} = -5 \text{ V}; \text{ I}_{C} = 0 \text{ A}$		-	-	-100	nA
h _{FE}	DC current gain	$V_{CE} = -2 \text{ V}; \text{ I}_{C} = -10 \text{ mA}$		200	-	-	
		$V_{CE} = -2 \text{ V}; \text{ I}_{C} = -100 \text{ mA}$	[1]	150	-	-	
		$V_{CE} = -2 \text{ V}; I_C = -500 \text{ mA}$	[1]	90	-	-	
V _{CEsat}	collector-emitter	$I_{C} = -10 \text{ mA}; I_{B} = -0.5 \text{ mA}$		-	-	-25	mV
	saturation voltage	$I_{C} = -200 \text{ mA}; I_{B} = -10 \text{ mA}$		-	-	-150	mV
		$I_{C} = -500 \text{ mA}; I_{B} = -50 \text{ mA}$	[1]	-	-	-250	mV
R _{CEsat}	equivalent on-resistance	$I_{C} = -500 \text{ mA}; I_{B} = -50 \text{ mA}$	<u>[1]</u>	-	300	500	mΩ
V _{BEsat}	base-emitter saturation voltage	$I_{C} = -500 \text{ mA}; I_{B} = -50 \text{ mA}$	<u>[1]</u>	-	-	-1.1	V
V _{BEon}	base-emitter turn-on voltage	$V_{CE} = -2 \text{ V}; \text{ I}_{C} = -100 \text{ mA}$	<u>[1]</u>	-	-	-0.9	V
f _T	transition frequency	$V_{CE} = -5 \text{ V}; I_C = -100 \text{ mA};$ f = 100 MHz		100	280	-	MHz
C _c	collector capacitance	$V_{CB} = -10 \text{ V}; \text{ I}_{E} = \text{i}_{e} = 0 \text{ A};$ f = 1 MHz		-	-	10	pF
Transistor	TR2: NPN						
I _{CBO}	collector-base cut-off current	$V_{CB} = 50 \text{ V}; \text{ I}_{\text{E}} = 0 \text{ A}$		-	-	100	nA
I _{CEO}	collector-emitter	$V_{CE} = 30 \text{ V}; \text{ I}_{B} = 0 \text{ A}$		-	-	1	μA
	cut-off current	$V_{CE} = 30 \text{ V}; \text{ I}_{B} = 0 \text{ A}; \text{ T}_{j} = 150 \ ^{\circ}\text{C}$		-	-	50	μA
I _{EBO}	emitter-base cut-off current	$V_{EB} = 5 \text{ V}; \text{ I}_{C} = 0 \text{ A}$		-	-	400	μA
h _{FE}	DC current gain	$V_{CE} = 5 \text{ V}; \text{ I}_{C} = 5 \text{ mA}$		30	-	-	
V _{CEsat}	collector-emitter saturation voltage	$I_{C} = 10 \text{ mA}; I_{B} = 0.5 \text{ mA}$		-	-	150	mV
V _{I(off)}	off-state input voltage	$V_{CE} = 5 \text{ V}; I_{C} = 100 \ \mu\text{A}$		-	1.1	0.8	V
V _{I(on)}	on-state input voltage	$V_{CE} = 0.3 \text{ V}; I_{C} = 10 \text{ mA}$		2.5	1.8	-	V
R1	bias resistor 1 (input)			7	10	13	kΩ
R2/R1	bias resistor ratio			0.8	1	1.2	
C _c	collector capacitance	$V_{CB} = 10 \text{ V}; I_E = i_e = 0 \text{ A}; f = 1 \text{ MHz}$		-	-	2.5	pF

[1] Pulse test: $t_p \le 300 \ \mu s; \delta \le 0.02$

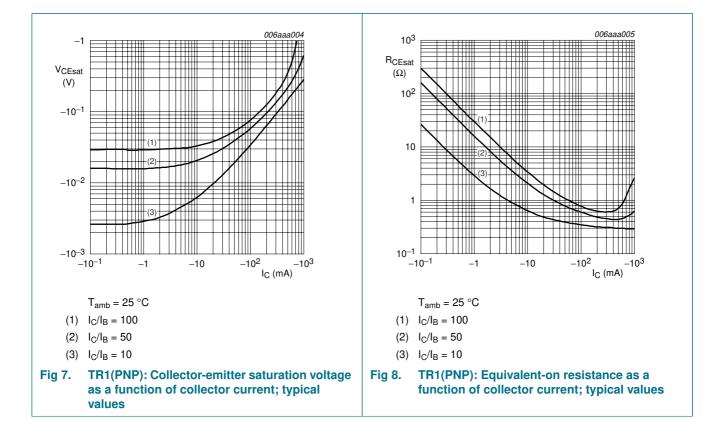
PBLS1503Y; PBLS1503V

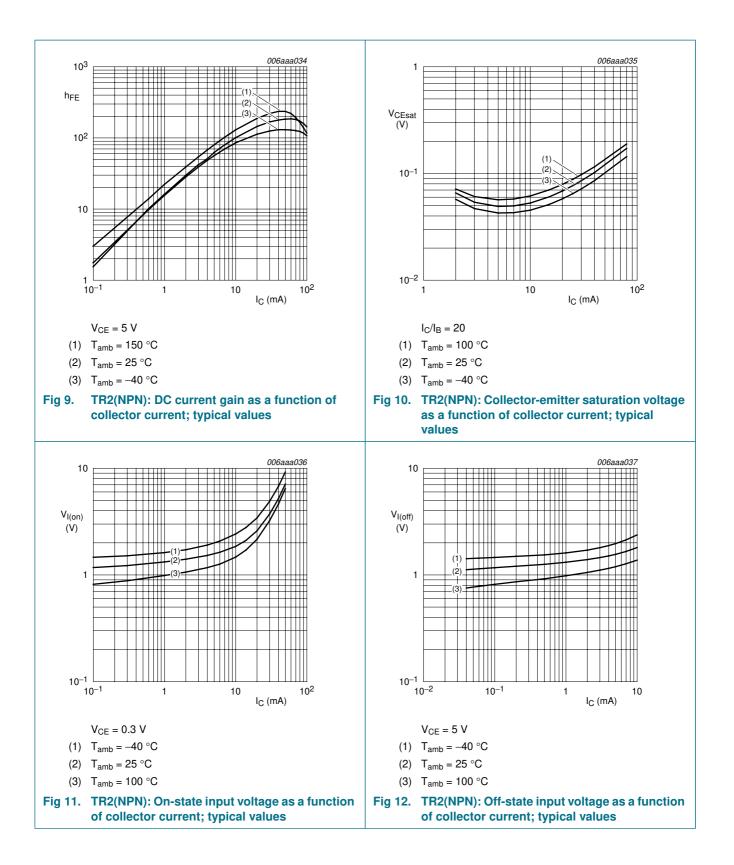


PBLS1503Y; PBLS1503V



PBLS1503Y; PBLS1503V





15 V PNP BISS loadswitch

8. Package outline

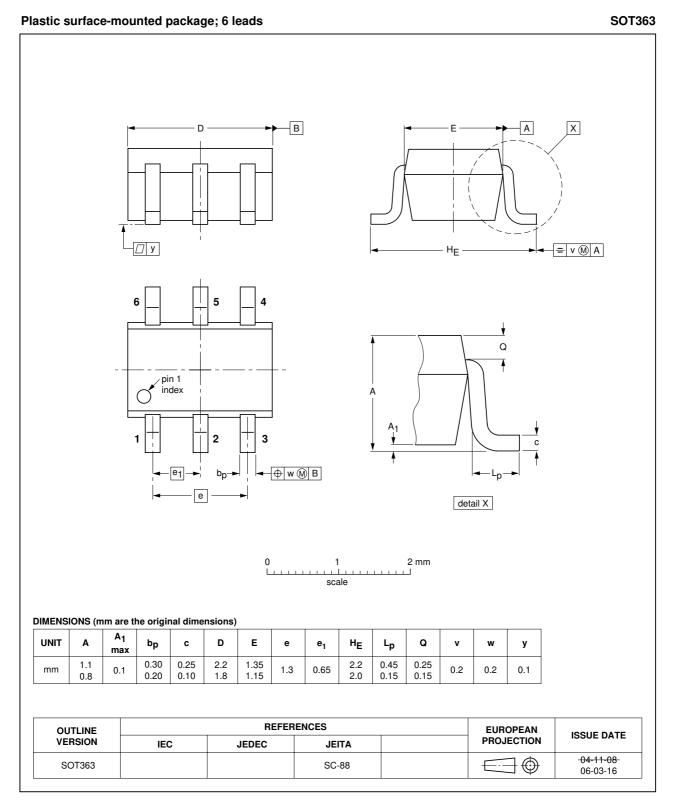


Fig 13. Package outline SOT363 (SC-88)

15 V PNP BISS loadswitch

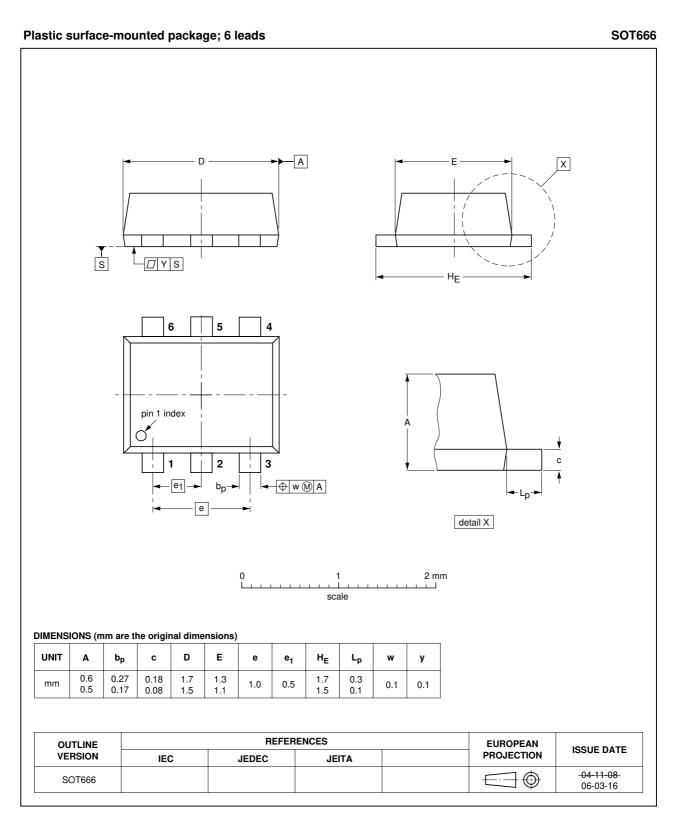


Fig 14. Package outline SOT666

PBLS1503Y_PBLS1503V_3

15 V PNP BISS loadswitch

9. Packing information

Table 9. Packing methods

The indicated -xxx are the last three digits of the 12NC ordering code.[1]

Type number	Package	Description		Packing qua	antity	
				3000	4000	10000
PBLS1503Y	SOT363	4 mm pitch, 8 mm tape and reel; T1	[2]	-115	-	–135
		4 mm pitch, 8 mm tape and reel; T2	[3]	-125	-	-165
PBLS1503V	SOT666	4 mm pitch, 8 mm tape and reel		-	-115	-

[1] For further information and the availability of packing methods, see Section 12.

[2] T1: normal taping

[3] T2: reverse taping

PBLS1503Y_PBLS1503V_3

10. Revision history

Release date	Data sheet status	Change notice	Supersedes
20090824	Product data sheet	-	PBLS1503Y_PBLS1503V_2
Table 3 "Disc	rete pinning": amended		
 Figure 13 "Page 	ackage outline SOT363 (So	C-88)": updated	
 Figure 14 "Page 	ackage outline SOT666": u	pdated	
20041125	Product data sheet	-	PBLS1503V_1
20021107	Product specification	-	
	Release date 20090824 • This data she including new content. • Table 3 "Disc • Figure 13 "Pa • Figure 14 "Pa	Release date Data sheet status 20090824 Product data sheet • This data sheet was changed to reflect including new legal definitions and disclement. • Table 3 "Discrete pinning": amended • Figure 13 "Package outline SOT363 (Souther Souther So	Release date Data sheet status Change notice 20090824 Product data sheet - • This data sheet was changed to reflect the new company rincluding new legal definitions and disclaimers. No change content. - • Table 3 "Discrete pinning": amended - • Figure 13 "Package outline SOT363 (SC-88)": updated - • Figure 14 "Package outline SOT666": updated - 20041125 Product data sheet -

11. Legal information

11.1 Data sheet status

Document status[1][2]	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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15 V PNP BISS loadswitch

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